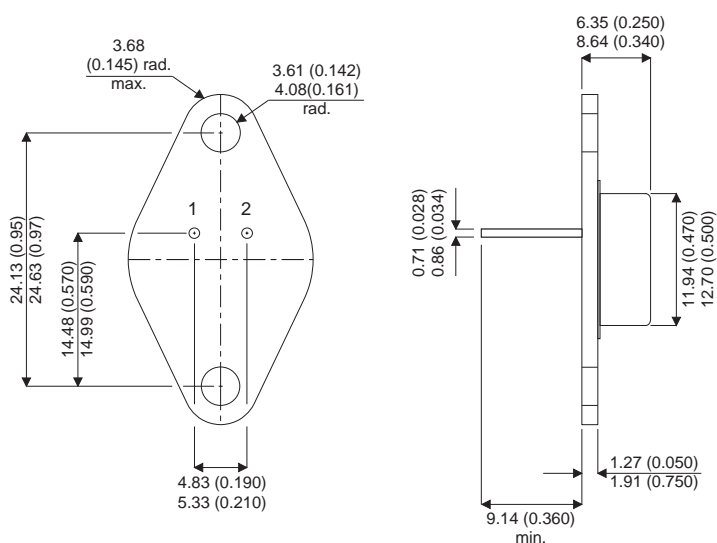


**MECHANICAL DATA**

Dimensions in mm



**POWER TRANSISTORS  
NPN SILICON**

**FEATURES**

- Hermetically Packaged.
- Low Saturation Voltage
- High Gain

**TO66 Package (TO-213AA)**

Pin 1 = Base      Pin 2 = Emitter      Case = Collector

**ABSOLUTE MAXIMUM RATINGS** ( $T_{case} = 25^{\circ}C$  unless otherwise stated)

$V_{CBO}$	Collector – Base Voltage	250V
$V_{CEO}$	Collector – Emitter Voltage ( $I_B = 0$ )	225V
$V_{EBO}$	Emitter – Base Voltage ( $I_C = 0$ )	6V
$I_C$	Collector Current	1A
$I_{C(PK)}$	Peak Collector Current	2A
$I_B$	Base Current	0.5A
$P_D$	Total Device Dissipation at $T_{case} = 25^{\circ}C$ Derate $25^{\circ}C$	20W 0.133W/ $^{\circ}C$
$T_{stg}$	Operating and Storage Temperature Range	$-65$ to $200^{\circ}C$

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**ELECTRICAL CHARACTERISTICS** ( $T_{\text{case}} = 25^{\circ}\text{C}$  unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
<b>ELECTRICAL CHARACTERISTICS</b>					
$V_{\text{CEO(BR)*}}$	Collector– Emitter Breakdown Voltage	$I_{\text{C}} = 5\text{mA}$ $I_{\text{B}} = 0$	225		V
$I_{\text{CBO}}$	Collector Base Cut–Off Current	$V_{\text{CB}} = 250\text{V}$ $I_{\text{E}} = 0$		0.1	mA
$I_{\text{CEO}}$	Collector Emitter Cut–Off Current	$V_{\text{CE}} = 125\text{V}$ $I_{\text{B}} = 0$		0.25	mA
$I_{\text{CEV}}$	Collector Cut–Off Current	$V_{\text{CE}} = 250\text{V}$ $V_{\text{BE(OFF)}} = 1.5\text{V}$		0.5	mA
		$V_{\text{CE}} = 125\text{V}$ $V_{\text{BE(OFF)}} = 1.5\text{V}$ $T_{\text{C}} = 100^{\circ}\text{C}$		1.0	mA
$I_{\text{EBO}}$	Emitter Base Cut–Off Current	$V_{\text{EB}} = 6\text{V}$		0.1	mA
$h_{\text{FE}*}$	DC Current Gain	$I_{\text{C}} = 50\text{mA}$ $V_{\text{CE}} = 10\text{V}$	30		—
		$I_{\text{C}} = 100\text{mA}$ $V_{\text{CE}} = 10\text{V}$	40	200	
		$I_{\text{C}} = 250\text{mA}$ $V_{\text{CE}} = 10\text{V}$	25		
$V_{\text{CE(sat)*}}$	Collector – Emitter Saturation Voltage	$I_{\text{C}} = 250\text{mA}$ $I_{\text{B}} = 25\text{mA}$		2.5	V
$V_{\text{BE(on)*}}$	Base – Emitter on Voltage	$I_{\text{C}} = 100\text{mA}$ $V_{\text{CE}} = 10\text{V}$		1.0	
<b>DYNAMIC CHARACTERISTICS</b>					
$f_{\text{T}}$	Transition Frequency	$I_{\text{C}} = 100\text{mA}$ $V_{\text{CE}} = 10\text{V}$ $f = 10\text{MHz}$	10		MHz
$C_{\text{ob}}$	Output Capacitance	$V_{\text{CB}} = 100\text{V}$ $I_{\text{E}} = 0$ $f = 100\text{KHz}$		20	pF
$h_{\text{fe}}$	Small Signal Current Gain	$I_{\text{C}} = 100\text{mA}$ $V_{\text{CE}} = 20\text{V}$ $f = 1\text{KHz}$	35		—

\* Pulse Width  $\leq 300\mu\text{s}$  , Duty Cycle  $< 2\%$

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